NSN 5962-01-350-2140

Memory Microcircuit - Page 1 of 2

Overall Length: 1.280 inches Overall Height:



View Online at https://aerobasegroup.com/nsn/5962-01-350-2140

0.400 inches	
Body Length:	
1.280 inches	
Body Width:	
Between 0.220 inches and 0.310 inches	
Body Height:	
Between 0.140 inches and 0.185 inches	
Maximum Power Dissipation Rating:	
1.0 watts	
Operating Tempurature Range:	
-55.0/+125.0 degrees celsius	
Storage Tempurature Range:	
-65.0/+150.0 degrees celsius	
Features Provided:	
Monolithic and w/enable and bidirectional	
Inclosure Material:	
Ceramic	
Inclosure Configuration:	
Dual-in-line	
Output Logic Form:	
Complementary-metal oxide-semiconductor logic	
Input Circuit Pattern:	
22 input	
Case Outline Source And Designator:	
D-9 mil-m-38510	
Current Rating Per Characteristic:	
120.00 milliamperes reverse current, dc absolute	
Terminal Surface Treatment:	
Solder	
Product Name:	
Sram	
Voltage Rating And Type Per Characteristic:	
-0.5 volts power source and 7.0 volts power source	е
Capitance Rating Per Characteristic:	
10.00 input picofarads and 12.00 output picofarad	s
Time Rating Per Chacteristic:	
55.00 nanoseconds af output megawatts	
Memory Device Type:	
Ram	

NSN 5962-01-350-2140

Memory Microcircuit - Page 2 of 2



Test	Data	Docum	ent
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96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

24 printed circuit

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Shelf Life: N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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